Metals



Flexible silver nanowire transparent conductive films prepared by an electrostatic adsorption self-assembly process

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ABSTRACT

In this work, we reported a facile approach to fabricate silver nanowire (AgNW) networks on flexible substrates. Through immersing the modified poly (ethylene terephthalate) with positively charged functional group into the AgNW dispersion with anionic dispersant, a flexible AgNW transparent conductive film was formed by electrostatic adsorption self-assembly process. Even without a post-treatment process, the as-prepared flexible AgNW films exhibited excellent optoelectrical property, low surface roughness and high reliability. It was shown that the insulating dispersant on AgNWs could be effectively removed by an ion bombardment method and then greatly decreased the sheet resistance of AgNW networks. Because of the nature of spontaneous adsorption, this preparation method can be suitable for an arbitrary shaped substrate, which will broaden the application of AgNW conductive films in optoelectronic devices.

Introduction

Transparent conductive films (TCFs) are essential components for many optoelectronic devices such as solar cells, liquid crystal displays, organic light emitting diodes and touch panels [1–4]. Due to the increasing need for wearable optoelectronic devices, the flexible and stretchable TCFs have been intensively studied [5]. Tin-doped indium oxide (ITO) has been widely used in commercial TCFs. However, due to indium resources scarcity, high process cost, high deposition temperature, and especially its intrinsic

brittleness, the usage of ITO will be seriously limited in emerging flexible optoelectronic devices [6]. Currently, there is an urgent need to develop the nextgeneration flexible TCFs. Many potential alternatives including graphene [7, 8], carbon nanotubes [9, 10], metal or metal nanowires [11–14] and hybrids of these [3, 15] have been paid high attention. Among of them, silver nanowires (AgNWs) possessing excellent optical and electrical properties, high mechanical robustness, good flexibility and comparatively high chemical stability are considered as one of the most promising candidates [6, 14, 16, 17]. In the past

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decade, a variety of methods had been presented to construct AgNW conductive films. The Meyer rod coating technique reported by Hu et al. [14] enabled scalable roll-to-roll deposition of AgNWs on a substrate. Selzer et al. [18] investigated a spray-coating process of AgNW conductive films. A dry transfer technique for transferring AgNW networks onto a flexible substrate was reported by Madaria et al. [19]. However, the above-mentioned methods encounter a difficulty that the films are only deposited on flat substrates with regular shape, which seriously limits the application of TCFs. In addition, without the usage of an organic binder or the mechanical pressure process, the prepared conductive films by these methods will usually suffer from poor adhesion between nanowires and flexible substrates. However, the binder can greatly increase the sheet resistance and the pressure treatment process can bring a risk of damaging weak flexible substrates.

The electrostatic adsorption method was early developed by Decher and others for the construction of ultrathin multilayer films of organic compounds [20–25]. Based on electrostatic adsorption principle, we proposed a novel preparation process of AgNW conductive films on flexible substrates. It was intended to produce an ultrathin film on the substrate through simply dipping a positively charged substrate into AgNW dispersion containing anion dispersant. This method is characterized by several significant advantages over the common methods. Firstly, the adhesion between substrates and AgNWs can be greatly enhanced by strong electrostatic adsorption [21]. Furthermore, since the process is based on spontaneous adsorption in solution, the AgNW networks can be formed on an arbitrary shaped substrate. For example, this process can coat AgNWs onto a cylindrical electrode, but the traditional methods cannot finish it. Therefore, this easily operated method is expected to expand the application of conductive films. The test results showed that the as-fabricated conductive films by this process possessed excellent optoelectrical performance, low surface roughness and high reliability.

It is known that the originally prepared AgNW films without a post-treatment may have a considerable sheet resistance (R_s), which will restrict its immediate application. This large sheet resistance is mainly resulted from both the contact resistance between the NWs–NWs and the insulating ligands on the nanowires. For reducing the contact resistance, a

large number of post-treatment processes such as thermal or mechanical pressing, flash-induced plasmonic welding and integration with other materials have been developed [14, 26–28]. However, up to date, it is still a difficulty to remove the insulating ligands on the nanowires after forming AgNW films. In this work, we tried to use an ion bombardment method to remove the non-conductive dispersant on the AgNWs. It was found that the sheet resistance could be reduced to a large extent after the AgNW film was cleaned by this method.

Experimental

Fabrication of AgNW dispersion

A mixture of 0.8 g of polyvinylpyrrolidone (PVP) (MW: 58000) and 31.2 g of 1,2-propylene glycol (PG) was heated to 125 °C and stirred for 15 min in a reaction vessel. Then, 1.1 g of tetrabutylammonium chloride (TBAC) solution, 1.0 g of catechol solution and 10.7 g of silver nitrate (AgNO₃) solution were added to the stirring mixture. After 140 min, 21.5 g AgNO₃ solution was dripped into the reaction vessel drop by drop over a period of 330 min. The obtained solution was cooled down to room temperature. The resulting solution was diluted with methanol and centrifuged three times at 8000 rpm for 10 min to remove PG, PVP and other impurities in the supernatant. Then, the precipitate of AgNWs and Zonyl[®] FSP (Dupont, China) were added into a vessel with a certain amount of deionized water, and the concentration of AgNW dispersion was controlled in $0.5-3 \text{ mg mL}^{-1}$. In addition, the weight ratio of the anionic dispersant and AgNWs was about 1:(10-30).

Graft polymerization onto poly (ethylene terephthalate) (PET) film

A mixture of 1.95 g of *N*, *N'*-(dimethylamino) ethyl methacrylate (DMAEMA), 3.12 g of 1-bromododecane ($R_{12}Br$) and 50 mL acetone was stirred for 5 h at 40 °C and quaternary amine monomer (DMAEMA- $R_{12}Br$) was successfully synthesized. A clean PET film was placed in a beaker containing 5 g DMAEMA- $R_{12}Br$, 0.01 g of meta-sodium periodate (NaIO₄) and 50 mL deionized water. Using ultraviolet (UV) radiation produced from a 1000 W high-pressure mercury lamp (Ergu Photoelectric Corporation, Shenzhen, China) irradiated the film at 40 °C for 3 h.

Ion bombardment treatment process

To reduce sheet resistance of the conductive film, ion bombardment produced by a precision ion etching system (RES 101, Leica, Germany) was used to remove non-conductive polymers of its surface. In addition, the system voltage and current were controlled in 1–2 kV and 0.5–1 mA, respectively.

Characterization

X-ray photoelectron spectrometer (XPS) (ESCALAB 250, Thermofisher VG, America) and Acid Orange 7 (98%, Aladdin Industrial Corporation, China) were used to detect the graft polymerization of DMAEMA-R₁₂Br onto PET films. The pristine AgNWs and redispersed AgNWs were characterized using Fourier transform infrared spectroscopy (FTIR) (NICO-LET 6700, Thermo Scientific, America) and XPS. Zeta potentials were measured by a ZS Zetasizer apparatus (Malvern Zetasizer Nano-ZS90, UK) and a solid surface zeta potential analyzer (SURPASS, Antor Paar, Austria). The morphologies of TCFs were characterized by scanning electron microscopy (SEM) (SUPRA 55 Sapphire, Zeiss, Germany) and the surface roughness was observed using an atomic force microscopy (AFM) (INNOVA, Bruker, Germany) with a tapping mode. The optical transmittance (T) was measured using a UV-NIR spectrophotometer (CARY 5000, Agilent, China), in which a bare substrate was used as a blank sample to acquire the transmittance data. The measurement of the sheet resistance was carried out on a 4-point probes resistivity measurement system (RTS-9, China). The cyclic bending test was performed using a custom-designed apparatus.

Results and discussion

The preparation process of the AgNW conductive film on PET substrate is schematically illustrated in Fig. 1a. Firstly, the graft polymerization of the PET film was achieved in aqueous solution with a reagent of quaternary amine monomers under the condition of UV radiation [29]. After graft polymerization, the modified PET film would be positively charged in solution. The as-prepared AgNWs were carefully cleaned and then dispersed in aqueous solution with an anionic surface-active agent of Zonyl[®] FSP. After ultrasonic and stirring processes, a stable AgNW dispersion could be obtained when the negatively charged molecules adsorbed on AgNWs. Then the modified PET film was dipped into the AgNW dispersion. By strong electrostatic adsorption, the AgNWs were deposited and formed a uniform network on the PET substrate. In this self-assembly process by electrostatic adsorption, the AgNW network density could be easily controlled by adjusting the amount of graft polymerization and the concentration of AgNW dispersion. A moderate density of AgNW networks could generate the optimum combination of sheet resistance and optical transmittance. On the other hand, it was worth noted that this film preparation process by spontaneous adsorption was not limited regarding the size and shape of substrates. Figure 1b shows the molecular structures of the applied anionic surfactant of Zonyl[®] FSP and cationic surfactant of DMAEMA-R₁₂Br.

In XPS analysis, the high-resolution spectra of C 1s, O 1s, N 1s and Br 3d regions of the virgin PET film and the modified PET film are shown in Fig. 2. The O 1s, N 1s and Br 3d intensities were normalized concerning the C 1s intensity. As shown in Fig. 2a, the C 1s spectrum of the virgin PET film could be divided into three peaks by curve fitting. The binding energies in three peaks were 284.6 eV, 286.2 eV and 288.6 eV, respectively, and it was known that the virgin film possessed three types of carbon functional groups, i.e., benzene ring, C–C–O and O–C=O. Based on the area ratio of carbon peaks, the ratio of carbon atoms in three functional groups was calculated to be 61:22:17, being nearly identical with the theoretical value of 60:20:20 [30]. The XPS O 1s core level spectrum of the virgin PET film contained two types of oxygen functional groups. They could be recognized as C–O (533.0 eV) and C=O (531.4 eV) by binding energy. The ratio of oxygen atoms in two functional groups was also consistent with the theoretical value [30]. Nevertheless, it was noted that there were no obvious peaks in the N 1s and Br 3d spectra of the virgin PET film. For the modified PET film, there were two new peaks in the C 1s spectrum compared with the virgin PET film, as shown in Fig. 2b. According to the binding energies of new peaks, it was determined that the corresponding functional groups were C-C (284.8 eV) and C-N (285.8 eV),



Figure 1 a Schematic of preparation process of AgNW network on PET film by electrostatic adsorption self-assembly method. b Molecular structures of two typical surfactants, $Zonyl^{\text{®}}$ FSP and DMAEMA-R₁₂Br.

respectively. These emerging functional groups clearly demonstrated that the modified PET film contained DMAEMA. Meanwhile, the O 1s spectrum also produced a new peak at the 532.3 eV (C-O-C). When the photoreactive group (C=O) of the PET substrate and the carbon–carbon double bond (C=C) of DMAEMA were cleft by UV irradiation, the opened chemical bonds could recombine into a new group of C–O–C. The presence of the C–O–C group testified that the DMAEMA had been successfully grafted onto the PET film. Moreover, there were also new peaks appearing in the N 1s and Br 3d spectra when the quaternary amine monomers were grafted onto the PET film. In particular, the single peak of quaternary amine at 402.3 eV in the N 1s spectrum suggested that the quaternization of DMAEMA was extremely complete.

When a virgin PET film and a modified PET film were immersed in 5×10^{-4} M aqueous Acid Orange 7 solution at 50 °C for 30 min, it was noted that the modified PET film could be dyed with the Acid Orange 7 and the virgin PET film could not be stained, as shown in Fig. 3. Since the Acid Orange 7 can be negatively charged in solution, it is often used to detect cationic surfactants by spectrophotometric [31]. When the Acid Orange 7 was adsorbed on the modified PET film, it demonstrated that the modified PET film had been successfully positively charged in solution.

The as-prepared AgNWs were carefully cleaned and then redispersed in aqueous solution with an anionic surface-active agent. To prove the anionic surfactant successfully adsorbed on AgNWs, XPS and FTIR spectra are used as shown in Fig. 4. In Fig. 4a, the C 1s core level spectrum clearly showed



Figure 2 XPS spectra of the PET film: a virgin film, b modified film (graft polymerization of DMAEMA-R₁₂Br onto PET film).



Figure 3 Photograph of virgin and modified PET films after dipped into Acid Orange 7 solution.

that pristine AgNWs possessed four types of carbon functional groups, i.e., C-N, C-C, C-H, N-C=O. This result demonstrated the pristine AgNWs containing PVP. It was noted that there was no obvious peak in the P 2p spectrum of the pristine AgNWs. For redispersed AgNWs, the C 1s spectrum contained five main types of carbon functional groups, which were clearly recognizable as C-C (284.6 eV), C-O (285.6 eV), CH₂-CF₂ (289.5 eV), CF₂-CF₂ (290.2 eV) and CF_3 (292.2 eV) by binding energy. In this study, the anion surfactant was required to adsorbed on AgNWs. According to the XPS C 1s spectrum, these new peaks (CH₂-CF₂, CF₂-CF₂ and CF₃) indicated the redispersed AgNWs contained the anionic surfaceactive agent (Zonyl[®] FSP). In addition, the new peak appearing in the P 2p spectrum was also consistent with the result, as shown in Fig. 4b. Figure 4c shows FTIR spectra of the pristine AgNWs and the redispersed AgNWs. Compared with the spectrum of the



Figure 4 XPS spectra of **a** pristine AgNWs, and **b** redispersed AgNWs. **c** FTIR spectra of redispersed AgNWs, compared with pristine AgNWs. **d** Zeta potentials of modified PET, redispersed AgNW dispersion and as-fabricated AgNW film.

pristine AgNWs, the weak peak at 1660.89 cm⁻¹ was in correspondence to amide I band (mainly C=O stretching), which indicated that the redispersed AgNWs still contained trace PVP. Moreover, in the spectrum of redispersed AgNWs, the strong peaks at 1204.70 and 1232.31 cm⁻¹ belonged to CF₂ absorption band. The characteristic peaks at 1143.21 and 1077.39 cm⁻¹ were attributed to P=O stretching and P–O–C bending, respectively. Meanwhile 3214.72 cm⁻¹ represented the existence of ammonium group. These results supported that the Zonyl[®] FSP was successfully adsorbed on AgNWs.

In this study, the prerequisite for obtaining high reliable conductive films was strong electrostatic adsorption between substrates and AgNWs. The most efficient way to determine this was by zeta potential measurement. As shown in Fig. 4d, when the PH was 7.0 and the temperature was 25 °C, the zeta potential of a modified PET film was ca.

+ 30 mV because of graft polymerization of DMAEMA- R_{12} Br onto PET film. Under the same condition, the zeta potential of the redispersed AgNW dispersion was ca. – 63 mV due to the anionic surfactant successfully adsorbed on AgNWs. After the modified PET film was dipped into the redispersed AgNW dispersion, the zeta potential of the as-fabricated conductive film was ca. – 6 mV, which demonstrated that the AgNWs were deposited on the PET substrate due to strong electrostatic adsorption.

Figure 5 shows morphologies of AgNW networks adsorbing on PET substrates. After the modified PET film was dipped into AgNW dispersion with the concentration of 1.5 mg mL⁻¹ for 20 min, the obtained AgNW networks had a sheet resistance of 50 Ω sq⁻¹ and an optical transmittance of 73%, as shown in Fig. 5a. With reducing the concentration of dispersion solution to 0.75 mg mL⁻¹, the density of

Figure 6 Optoelectrical

performance comparison between AgNW films in this

films.

work and reported conductive



Figure 5 SEM images of AgNW networks on PET substrates by electrostatic adsorption process. The different densities of the AgNW networks lead to different sheet resistance: **a** 50 Ω sq⁻¹,

and **b** 116 Ω sq⁻¹. Inset was a photograph of the as-fabricated nanowire network on a 2 cm \times 2 cm PET substrate.



the formed AgNW networks was obviously decreased, as shown in Fig. 5b. The sheet resistance and optical transmittance were measured to be 116 Ω sq⁻¹ and 81%, respectively. It revealed that the density of AgNW networks could be effectively controlled by adjusting the concentration of the dispersion solution. The optimal concentration of AgNW dispersion should be $0.5-3 \text{ mg mL}^{-1}$. In addition, the SEM images also revealed that the AgNW network by this electrostatic adsorption process was rather uniform over the entire PET substrate. The inset was a photograph of the asfabricated nanowire network on a 2 cm \times 2 cm PET substrate. The pattern in the background could be clearly seen through this film, indicating that the film was highly transparent. On the other hand, it was noted that the type and quantity of dispersant had a serious influence on the sheet resistance of the

prepared AgNW films by electrostatic adsorption process. To obtain high-quality conductive films, the weight ratio of the added anionic dispersant and AgNWs should be controlled to be about 1:(10–30) in the AgNW dispersion.

The comparison of optoelectrical property between the present work and the previous reports is plotted as shown in Fig. 6. The fabricated AgNW—graphene nanosheets (GNs) (1:1) hybrid conductive film using an electrostatic adsorption process had an optical transmittance 82% and a sheet resistance of 1500 Ω sq⁻¹ [32]. The another multilayer conductive film of the reduced graphene oxide/silver nanoparticles (RGO/Ag NPs) had a high sheet resistance of 7000 Ω sq⁻¹ at an optical transmittance of 78% [33]. Obviously, in the case of similar optical transmittance, the sheet resistance of the present AgNW film ($R_s = 116 \Omega$ sq⁻¹ with T = 81%) was far lower than those of the graphene or graphene–silver hybrid films. The reported AgNW conductive films by Meyer rod coating technique and a dry transfer technique shown in Fig. 6 had relatively excellent optoelectrical performance [14, 19]. However, the films prepared by these methods might suffer from poor adhesion between AgNW networks and substrates if not the application of binder or mechanical pressure treatment. Besides that, these methods could



Figure 7 a Schematic illustration of ion bombardment process to remove dispersant on AgNW films. **b** Change of sheet resistance versus transmittance at 550 nm for AgNW films after ion bombardment.

only fabricate the AgNW networks on flat substrates with regular shape.

As for the preparation of AgNW dispersion, one of the available strategies to obtain an excellent optoelectrical performance is to synthesize high aspect ratio nanowires [34]. The other approach is to reduce the insulating ligands covered on nanowires because these organic compounds will greatly increase sheet resistance of AgNW films [35]. In practical, it is extremely difficult to remove the organic dispersant on nanowires after forming conductive films. For removing the dispersant on AgNW films, an ion bombardment method was employed in this work, as schematically illustrated in Fig. 7a. When the gas argon was ionized into positively charged argon ions (Ar^+) with enough high energy and then bombarded the surface of the sample, the insulating ligands on the surface could be sputtered and break away from the surface. The plot of sheet resistance versus optical transmittance of the as-prepared AgNW films before and after ion bombardment treatment is shown in Fig. 7b. For any a selected sample prepared in AgNW dispersion with different concentration and amounts of dispersant, the sheet resistance was obviously reduced while the optical transmittance was almost unchanged after ion bombardment treatment. For example, the sample with a large amount of dispersant had a high sheet resistance of 2361 Ω sq⁻¹. After ion bombardment, the sheet resistance was decreased to 45 Ω sg⁻¹ and the transmittance was still 70%. In comparison, the samples with a small amount of dispersant had a relatively small decrease in sheet resistance after ion bombardment. The results reflected the effectiveness of ion bombardment on removing the dispersant on AgNW films.

Table 1 shows the sheet resistance of the AgNW films after different ion bombardment time. It was noteworthy that the sheet resistance decreased to a lowest value and then began to increase with the

Table 1 Sheet resistancechange of the AgNWconductive films for varied ionbombardment treatment time

Sample	Sheet resistance (Ω sq ⁻¹) with varied ion bombardment time (s)					
	0	60	90	180	240	300
Sample1	23	18.1	15.1	38.8		
Sample2	1800		81.2	48.0	33.1	52.5
Sample3	50	39.1	32.5	55.3		
Sample4	451		85.4	45.2	71.3	

increasing bombardment time. It was thought that the over-long time treatment could damage the silver nanowire network, which would increase the sheet resistance. Additionally, the bombardment time to reach the minimum sheet resistance was different among these samples. The required bombardment time to obtain optimum optoelectrical performance was related to the amount of the dispersant adsorbed on nanowires.



Figure 8 AFM image of the AgNW film prepared by electrostatic adsorption self-assembly process. The scale range was $20 \ \mu m \times 20 \ \mu m$.

Surface roughness is one of crucial property parameters for the application of TCFs. It was reported that the solution processed AgNW conductive films often exhibited high surface roughness if not a post-treatment process [36]. In contrast to the common spinning coating or Meyer rod coating process [14, 37], this self-assemble process was capable of forming monolayer films and building a nearly flat AgNW network. Therefore, the conductive film prepared by the present method could possess a relatively low surface roughness. As shown in Fig. 8, the surface roughness value was measured to be 25.2 nm. Such a low surface roughness could allow for strong bonding force and be well compatible with high-efficiency optoelectronic devices.

The reliability of the as-fabricated flexible conductive films was evaluated by a cyclic bending test on a custom-designed apparatus (inset in Fig. 9b). When a cyclic bending loading with 10 mm bending radius was carried out on the as-prepared sample, the change of the normalized resistance (R/R_0) was monitored in real time, as shown in Fig. 9a. It was shown that the change of R/R_0 was almost unnoticeable after 10000 cycles. Also, the bending radius had hardly effect on the resistance of the conductive films, as shown in Fig. 9b. After the high-cycle bending fatigue, the AgNW network was not detected to be damaged or detached from the substrate. Even without the usage of binder, the cohesion between AgNW networks and PET substrates was quite reliable due to the strong electrostatic adsorp-



Figure 9 a The R/R_0 change with the bending cycles at the bending radius of 10 mm. b The R/R_0 values after 1000 bending cycles with various bending radius. Inset showed a custom-designed bending test apparatus.

tion. This flexible AgNW conductive film prepared by electrostatic adsorption method showed a potential application in the future flexible devices.

Conclusions

In this work, a flexible AgNW conductive network on PET substrate was fabricated by an electrostatic adsorption self-assembly process. The electrostatic adsorption self-assembly process was accomplished by immersing the modified PET into the AgNW dispersion with anionic dispersant. Without a posttreatment process, the formed AgNW network on PET substrate could achieve a relatively low sheet resistance of 116 Ω sq⁻¹ at *T* = 81%. The sheet resistance of the AgNW films could be further decreased to $45.3 \Omega \text{ sq}^{-1}$ when the insulating ligands on AgNWs were removed by an ion bombardment method. In addition, the test results showed that the as-prepared flexible AgNW films had low surface roughness and high reliability. Since this method is easily operated and independent on the shape and size of the substrate, it is expected to broaden the application range of AgNW conductive films in optoelectronic devices.

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Compliance with ethical standards

Conflict of interest The authors declare that they have no conflict of interest.

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